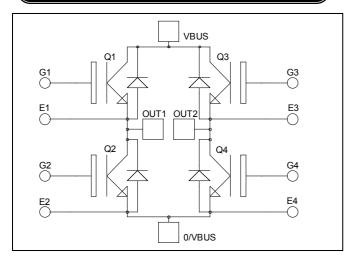
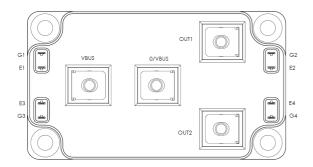


Full - Bridge Trench + Field Stop IGBT3 Power Module







Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1700	V
I_{C}	Continuous Collector Current	$T_C = 25$ °C	150	
	Continuous Conector Current	$T_C = 80$ °C	100	A
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	560	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	200A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				350	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		2.0	2.4	V
		$I_C = 100A$ $T_j =$	$T_j = 125$ °C		2.4		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 2mA$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				500	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			9		
C_{oes}	Output Capacitance				0.36		nF
C_{res}	Reverse Transfer Capacitance				0.3		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		370		
T_{r}	Rise Time	$V_{GE} = 15V$			40		
$T_{d(off)} \\$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 100A$			650		ns
T_{f}	Fall Time	$R_G = 4.7 \Omega$		180			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 900V$ $I_{C} = 100A$ $R_{G} = 4.7 \Omega$			400		ns
T_{r}	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				800		
T_{f}	Fall Time				300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 900V$	$T_j = 125$ °C		32		ma I
E_{off}	Turn-off Switching Energy	$I_C = 100A$ $R_G = 4.7 \Omega$	$T_j = 125$ °C		31		mJ

Diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1700V	$T_j = 25^{\circ}C$			350	μA
1RM			$T_{j} = 125^{\circ}C$			600	μΛ
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		100		A
V_{F}	Diode Forward Voltage	$I_F = 100A$	$T_i = 25^{\circ}C$		1.8	2.2	V
V F			$T_{i} = 125^{\circ}C$		1.9		
t_{rr}	Reverse Recovery Time	$I_F = 100A$ $V_R = 900V$ $di/dt = 1600A/\mu s$	$T_j = 25^{\circ}C$		385		ns
·rr			$T_j = 125$ °C		490		115
Q_{rr}	Reverse Recovery Charge		$T_j = 25^{\circ}C$		28		μC
Qrr			$T_{j} = 125^{\circ}C$		46		μС
E_{r}	Reverse Recovery Energy		$T_j = 25^{\circ}C$		12		mJ
			$T_{\rm j} = 125^{\circ}{\rm C}$		24		1117

APTGT100H170G = Rev 2 October 2012

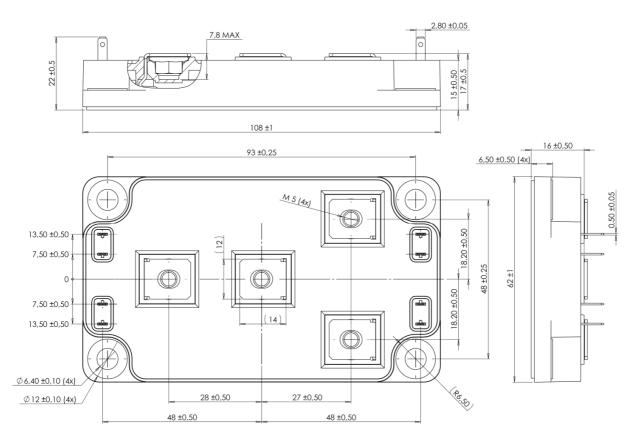
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Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance IGBT Diode				0.22	°C/W	
			Diode			0.39	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight	•				300	g

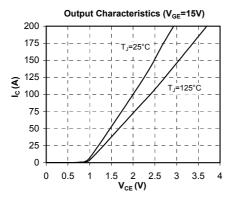
SP6 Package outline (dimensions in mm)

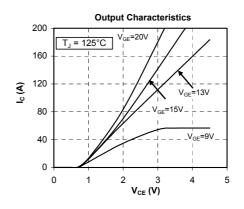


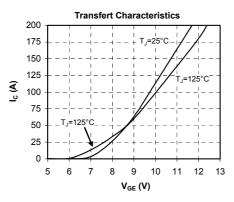
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

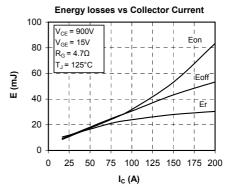


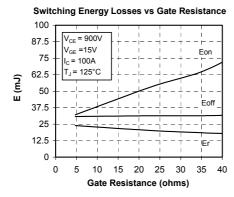
Typical Performance Curve

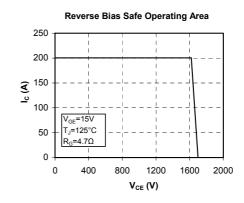


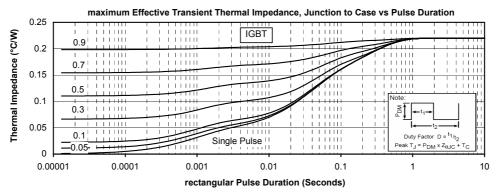




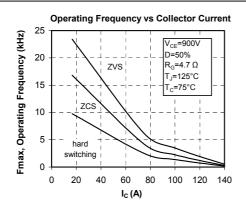


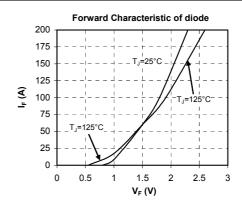


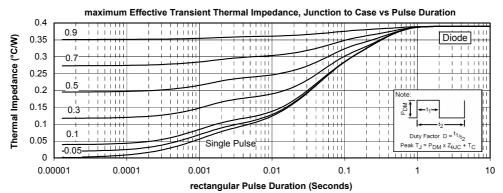














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